

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

N-Channel Silicon MOSFET

CPH6444 — General-Purpose Switching Device **Applications**

Features

- · Low ON-resistance.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		4.5	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	18	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² X0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =60V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2A	1.8	3		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=2A, VGS=10V		60	78	mΩ
	R _{DS} (on)2	I _D =1A, V _G S=4.5V		74	104	mΩ
	Rps(on)3	ID=1A, VGS=4V		81	114	mΩ

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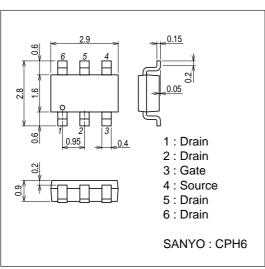
CPH6444

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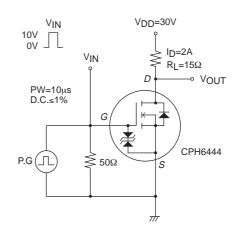
Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		505		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		57		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		37		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		7.3		ns
Rise Time	t _r	See specified Test Circuit.		9.8		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		40		ns
Fall Time	tf	See specified Test Circuit.		24		ns
Total Gate Charge	Qg	V _{DS} =30V, V _{GS} =10V, I _D =4.5A		10		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =4.5A		1.6		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =30V, V _{GS} =10V, I _D =4.5A		2.1		nC
Diode Forward Voltage	V _{SD}	I _S =4.5A, V _G S=0V		0.83	1.2	V

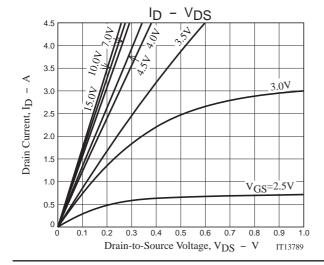
Package Dimensions

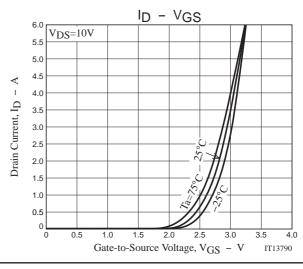
unit : mm (typ) 7018A-003

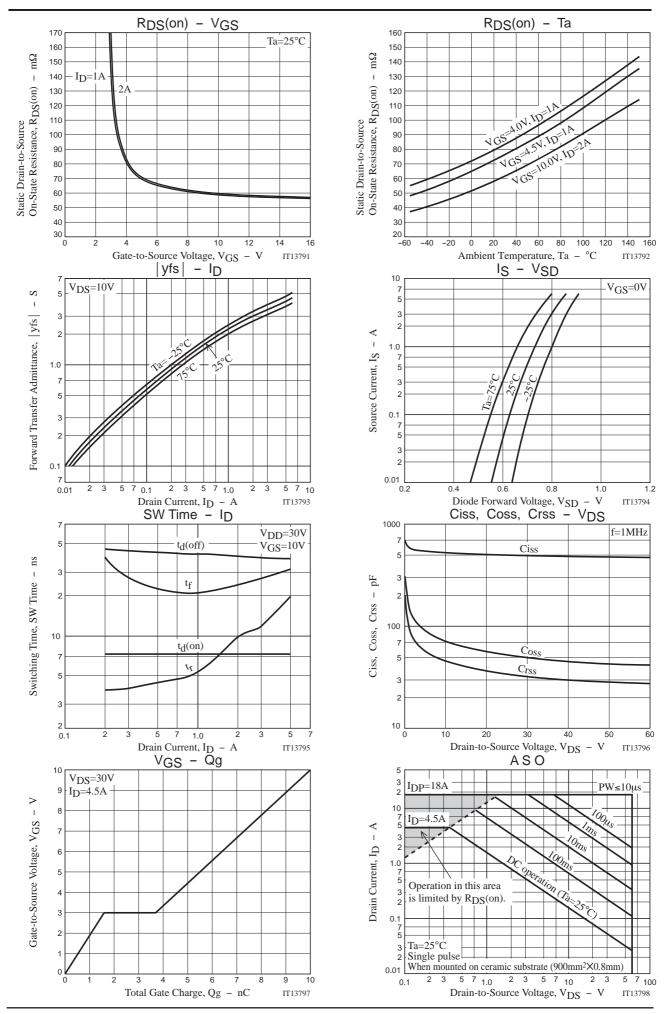


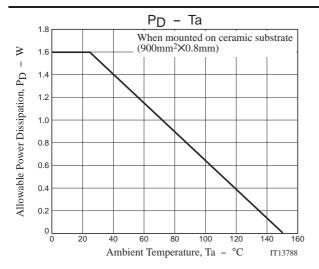
Switching Time Test Circuit











Note on usage: Since the CPH6444 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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